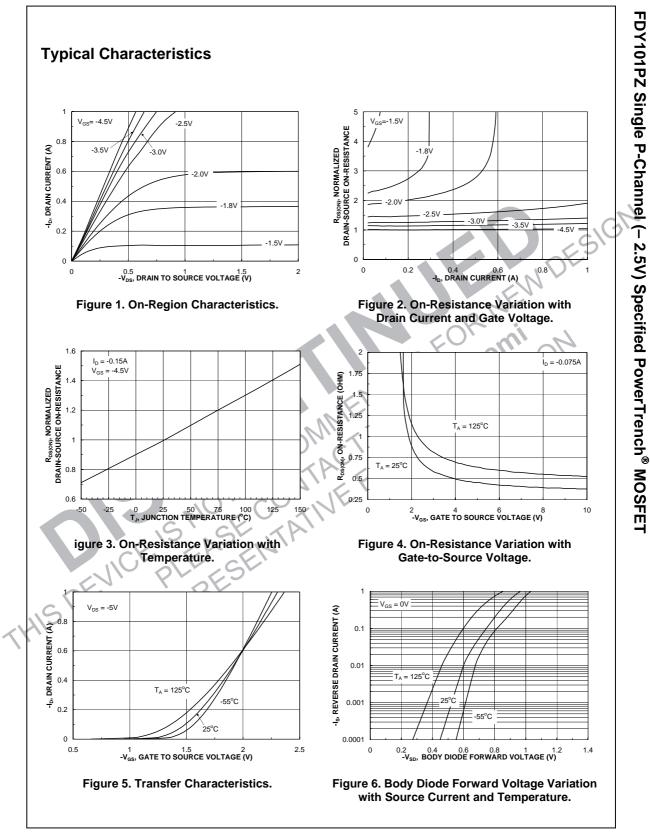


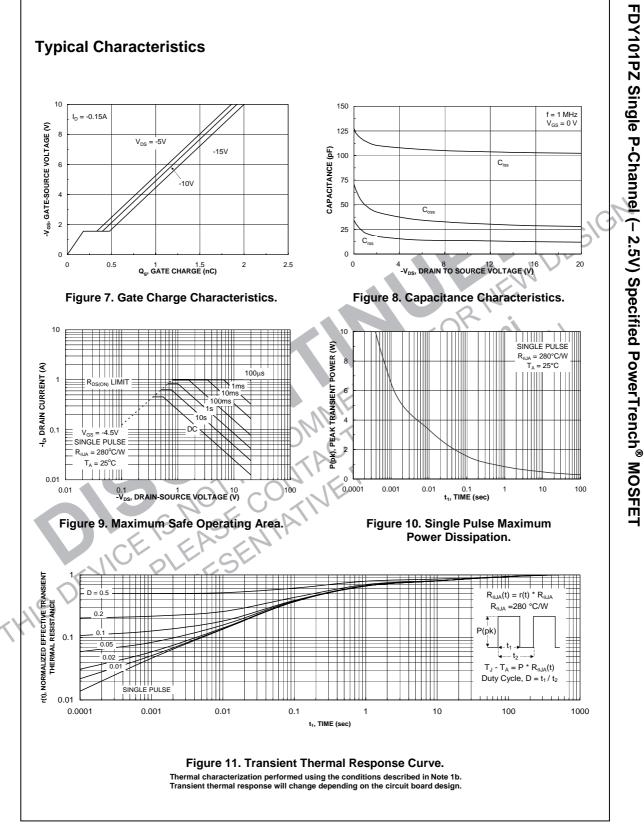
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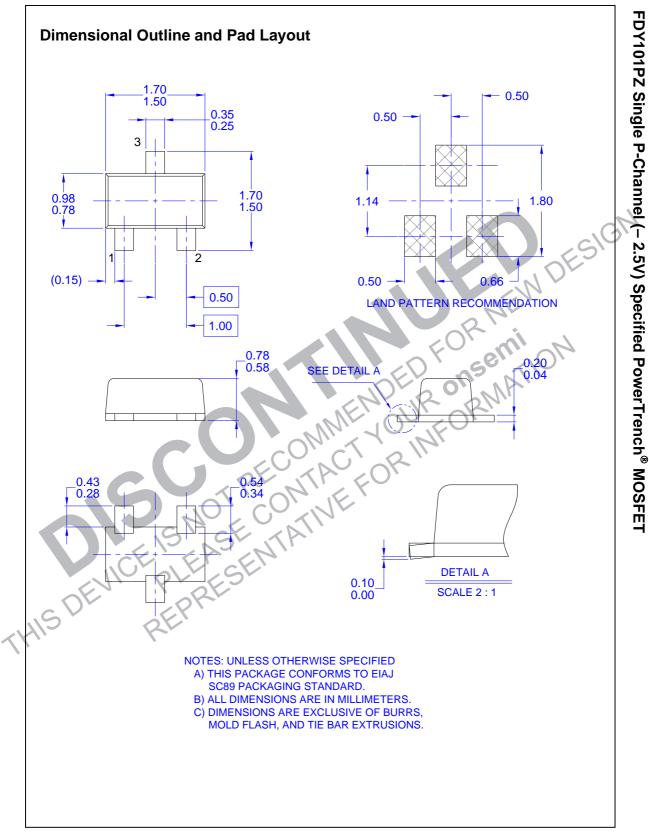
	al Characteristics	$T_A = 25^{\circ}C$ unless otherwise noted	1			
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \qquad I_D = -250 \mu\text{A}$	- 20			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25°C		15		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V},  V_{GS} = 0 \text{ V}$			- 3	μΑ
GSS	Gate–Body Leakage,	$V_{GS} = \pm 8 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			± 10	μΑ
On Chara	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = -250 \ \mu A$	- 0.65	- 1.0	- 1.5	V
<u>ΔV<sub>GS(th)</sub></u> ΔT <sub>J</sub>	Gate Threshold Voltage Temperature Coefficient	$I_D$ = 250 µA, Referenced to 25°C		-3		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS}=-4.5 \ V, \ \ I_{D}=-150 \ mA \\ V_{GS}=-2.5 \ V, \ \ I_{D}=-125 \ mA \\ V_{GS}=-1.8 \ V, \ \ I_{D}=-100 \ mA \\ V_{GS}=-1.5 \ V, \ \ I_{D}=-30 \ mA \\ V_{GS}=-4.5 \ V, \ \ I_{D}=-150 \ mA, \\ T_{J}=125^{\circ}C \end{array} $		N	8 12 15 20 12	Ω
<b>g</b> <sub>FS</sub>	Forward Transconductance	$V_{DS} = -5 V$ , $I_D = -150 \text{ mA}$		0.7		S
Dvnamic	Characteristics		50	2		7
C <sub>iss</sub>	Input Capacitance	$V_{DS} = -10 V$ , $V_{GS} = 0 V$ ,		100	<u> </u>	pF
Coss	Output Capacitance	f = 1.0  MHz	0,	30		pF
C <sub>rss</sub>	Reverse Transfer Capacitance		+ 0	15		pF
						P.
	g Characteristics (Note 2) Turn–On Delay Time	$V_{DD} = -10 \text{ V}, \ I_D = -0.5 \text{ A},$	X	6	12	ns
t <sub>d(on)</sub> t <sub>r</sub>	Turn–On Rise Time	$V_{\text{DD}} = -10$ V, $T_{\text{D}} = -0.3$ A, $V_{\text{GS}} = -4.5$ V, $R_{\text{GEN}} = 6$ $\Omega$		13	23	ns
	Turn–Off Delay Time			8	16	ns
t <sub>d(off)</sub>	Turn-Off Fall Time	NIF		1	2	
t <sub>f</sub>		1010 L 150 mA		1.0	 1.4	ns nC
Q <sub>g</sub>	Total Gate Charge	$V_{DS} = -10 \text{ V},  I_D = -150 \text{ mA}, \\ V_{GS} = -4.5 \text{ V}$		-	1.4	-
Q <sub>gs</sub>	Gate-Source Charge			0.2		nC
Q <sub>gd</sub>	Gate-Drain Charge			0.3		nC
	ource Diode Characteristics					
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \text{ V},  I_S = -150 \text{ mA}(\text{Note 2})$		- 0.8	- 1.2	V
t <sub>rr</sub>	Diode Reverse Recovery Time	$I_{\rm F} = -150  {\rm mA},$		11		ns
Q <sub>rr</sub>	Diode Reverse Recovery Charge	dl <sub>F</sub> /dt = 100 A/µs		2		nC
	a) to of the junction-to-case and case-to-ambient the auc is guaranteed by design while R <sub>eCA</sub> is determine a) 200°C/W who mounted on a of 2 oz copper	ned by the user's board design. en a 1in <sup>2</sup> pad	b) 280°C/M minimun Scale 1 2. Pulse Te	/ when mo n pad of 2 : 1 on lette	ounted on a oz copper er size pap Width < 30	a er

FDY101PZ Single P-Channel (– 2.5V) Specified PowerTrench<sup>®</sup> MOSFET

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